## **Power MOSFET**

# 500 mA, 60 V, N-Channel SOT-23

#### **Features**

- NVBF Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

## **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Drain-Source Voltage	$V_{DSS}$	60	Vdc
Drain-Gate Voltage	V <sub>DGS</sub>	60	Vdc
Gate-Source Voltage - Continuous - Non-repetitive (t <sub>p</sub> ≤ 50 μs)	V <sub>GS</sub> V <sub>GSM</sub>	±20 ±40	Vdc Vpk
Drain Current - Continuous - Pulsed	I <sub>D</sub> I <sub>DM</sub>	0.5 0.8	Adc

## THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board (Note 1.) T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	225 1.8	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	556	°C/W
Junction and Storage Temperature	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. FR-5 = 1.0  $\times$  0.75  $\times$  0.062 in.



## ON Semiconductor®

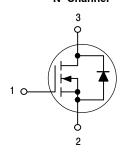
http://onsemi.com

500 mA, 60 V  $R_{DS(on)} = 5 \Omega$ 

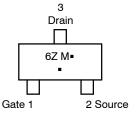


SOT-23 CASE 318 STYLE 21

#### N-Channel



# MARKING DIAGRAM & PIN ASSIGNMENT



6Z = Specific Device Code

M = Date Code ■ = Pb-Free Package

(Note: Microdot may be in either location)

## **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

## **ELECTRICAL CHARACTERISTICS** (T<sub>C</sub> = 25°C unless otherwise noted)

	Symbol	Min	Max	Unit	
OFF CHARACTERISTICS	3	•	•		•
Drain-Source Breakdowr	n Voltage (V <sub>GS</sub> = 0, I <sub>D</sub> = 100 μA)	V <sub>(BR)DSS</sub>	60	-	Vdc
Gate-Body Leakage Cur	I <sub>GSS</sub>	-	10	nAdc	
ON CHARACTERISTICS	(Note 1)				
Gate Threshold Voltage (	V <sub>GS(th)</sub>	0.8	3.0	Vdc	
Static Drain-Source On-	r <sub>DS(on)</sub>	-	5.0	Ω	
On-State Drain Current (	I <sub>D(off)</sub>	-	0.5	μΑ	
DYNAMIC CHARACTERI	STICS				
Input Capacitance (V <sub>DS</sub> = 10 Vdc, V <sub>GS</sub> = 0	C <sub>iss</sub>	-	60	pF	
SWITCHING CHARACTE	RISTICS (Note 1)				
Turn-On Delay Time	$(V_{DD} = 25 \text{ Vdc}, I_D = 500 \text{ mA}, R_{qen} = 50 \Omega)$	t <sub>d(on)</sub>	-	10	ns
Turn-Off Delay Time	Figure 1	t <sub>d(off)</sub>	-	10	

<sup>1.</sup> Pulse Test: Pulse Width  $\leq$  300  $\mu$ s, Duty Cycle  $\leq$  2.0%.

## **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>		
MMBF170LT1G	SOT-23 (TO-236) (Pb-Free)	3000 / Tape & Reel		
MMBF170LT3G	SOT-23 (TO-236) (Pb-Free)	10000 / Tape & Reel		
NVBF170LT1G*	SOT-23 (TO-236) (Pb-Free)	3000 / Tape & Reel		

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

<sup>\*</sup>NVBF Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.

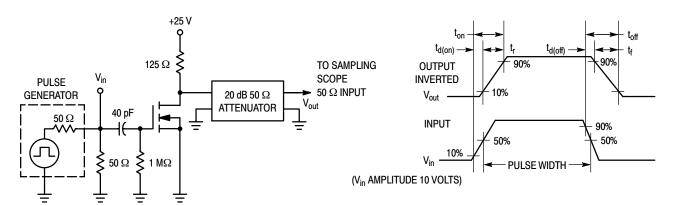
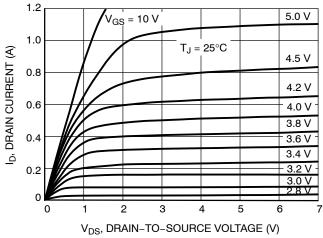


Figure 1. Switching Test Circuit

Figure 2. Switching Waveform

## TYPICAL ELECTRICAL CHARACTERISTICS



V<sub>DS</sub>, DRAIN-TO-SOURCE VOLTAGE (V)

Figure 3. On-Region Characteristics

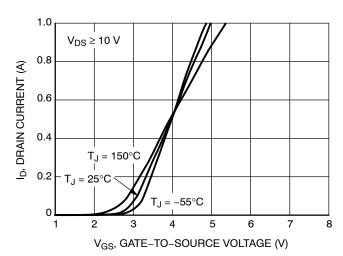


Figure 4. Transfer Characteristics

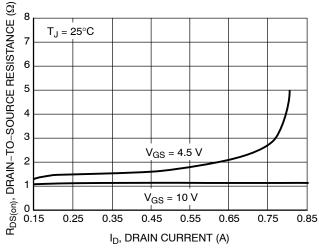


Figure 5. On-Resistance vs. Drain Current and Gate Voltage

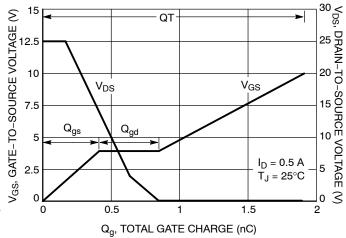


Figure 6. Gate-to-Source and Drain-to-Source Voltage vs. Total Charge

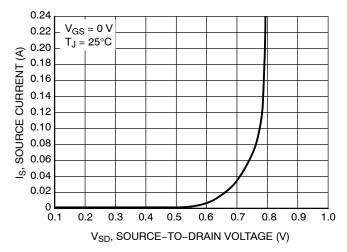


Figure 7. Diode Forward Voltage vs. Current

## TYPICAL ELECTRICAL CHARACTERISTICS

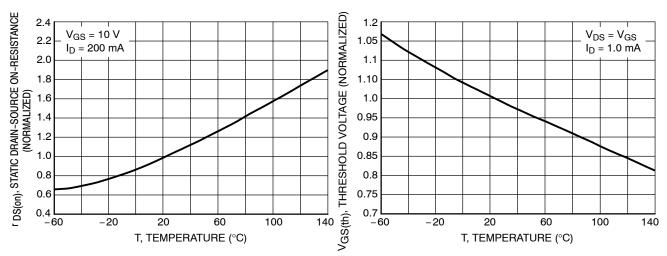
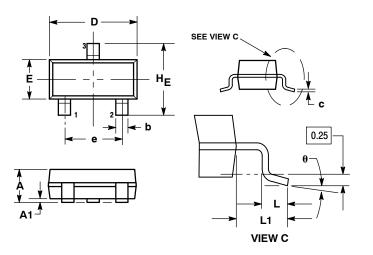


Figure 8. Temperature versus Static Drain-Source On-Resistance

Figure 9. Temperature versus Gate Threshold Voltage

## PACKAGE DIMENSIONS

## SOT-23 (TO-236) CASE 318-08 **ISSUE AP**



#### NOTES:

- NOTES:

  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

  2. CONTROLLING DIMENSION: INCH.

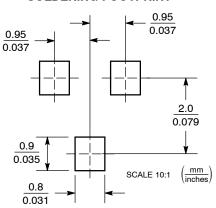
  3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH
  THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
  DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH,
- PROTRUSIONS, OR GATE BURRS

	MILLIMETERS		INCHES			
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.89	1.00	1.11	0.035	0.040	0.044
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.37	0.44	0.50	0.015	0.018	0.020
С	0.09	0.13	0.18	0.003	0.005	0.007
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
е	1.78	1.90	2.04	0.070	0.075	0.081
L	0.10	0.20	0.30	0.004	0.008	0.012
L1	0.35	0.54	0.69	0.014	0.021	0.029
HE	2.10	2.40	2.64	0.083	0.094	0.104
θ	0°		10°	0°		10°

STYLE 21: PIN 1. GATE

2. SOURCE DRAIN

#### **SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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